NSN 5961-01-522-5703

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-522-5703 **Inclosure Material:** Plastic **Overall Length:** Between 0.160 inches and 0.180 inches **Overall Height:** Between 0.084 inches and 0.096 inches **Overall Width:** Between 0.130 inches and 0.155 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-214aa **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 56.70 breakdown voltage, dc and 62.70 breakdown voltage, dc **Current Rating Per Characteristic:** 7.30 amperes source cutoff current pascal **Terminal Type And Quantity:** 2 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No